## NSN 5961-01-080-1494



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-080-1494 **Inclosure Material:** Metal **Overall Length:** Between 0.185 inches and 0.215 inches Overall Diameter: Between 0.270 inches and 0.290 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 collector to base voltage/static/emitter open and 45.0 collector to emitter reverse voltage and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 0.35 amperes source cutoff current **Power Rating Per Characteristic:** 7.2 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 45413-134764 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a **Unit Of Measure:** 

Fiig: A110a0

No

**Demilitarization:**